DATA SHEET

## Signal Diodes

| Order code | Manufacturer code | Description |
| :---: | :---: | :---: |
| $47-2904$ | BAT43 | BAT43 30V SILICON SCHOTTKY DIODE (ST) RC |


| Signad Diodes | Page 1 of |
| :---: | :---: |
| The enclosed information is believed to be correct, Intormation may change 'without notice' due to | Revision A |
| product improvement. Users should ensure that the product is suitable for their use. E. \& O. E. | $12 / 12 / 2006$ |

BAT42 BAT43

## SMALL SIGNAL SCHOTTKY DIODES

## DESCRIPTION

General purpose, metal to silicon diodes featuring very low turn-on voltage fast switching.
These devices have integrated protection against excessive voltage such as electrostatic dis-


ABSOLUTE RATINGS (limiting values)

| Symbol | Parameter | Value | Unit |  |
| :---: | :--- | :--- | :---: | :---: |
| $\mathrm{V}_{\text {RRM }}$ | Repetitive Peak Reverse Voltage | 30 | V |  |
| $\mathrm{I}_{\mathrm{F}}$ | Forward Continuous Current | $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ | 200 | mA |
| $\mathrm{I}_{\text {FRM }}$ | Repetitive Peak Fordware Current | $\mathrm{t}_{\mathrm{p}} \leq 1 \mathrm{~s}$ <br> $\delta \leq 0.5$ | 500 | mA |
| $\mathrm{I}_{\text {FSM }}$ | Surge non Repetitive Forward Current ${ }^{\star}$ | $\mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$ | 4 | A |
| $\mathrm{P}_{\text {tot }}$ | Power Dissipation* | $\mathrm{T}_{\mathrm{I}}=65^{\circ} \mathrm{C}$ | 200 | mW |
| $\mathrm{~T}_{\text {stg }}$ | Storage and Junction Temperature Range | -65 to +150 <br> $\mathrm{~T}_{\mathrm{j}}$ | 65 to +125 | ${ }^{\circ} \mathrm{C}$ <br> ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | Maximum Temperature for Soldering during 10 s at 4 mm from <br> Case | 230 | ${ }^{\circ} \mathrm{C}$ |  |

## THERMAL RESISTANCE

| Symbol | Test Conditions | Value | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\mathrm{th}(\mathrm{j}-\mathrm{a})}$ | Junction-ambient $^{*}$ |  | 300 |
| ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |  |  |  |

* On infinite heatsink with 4 mm lead length


## ELECTRICAL CHARACTERISTICS

## STATIC CHARACTERISTICS

| Symbol | Test Conditions |  |  | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{\text {BR }}$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{R}}=100 \mu \mathrm{~A}$ |  | 30 |  |  | V |
| $\mathrm{VF}^{*}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | $\mathrm{IF}=200 \mathrm{~mA}$ | All Types |  |  | 1 | V |
|  | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ | BAT 42 |  |  | 0.4 |  |
|  | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{F}}=50 \mathrm{~mA}$ |  |  |  | 0.65 |  |
|  | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{F}}=2 \mathrm{~mA}$ | BAT 43 | 0.26 |  | 0.33 |  |
|  | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{F}}=15 \mathrm{~mA}$ |  |  |  | 0.45 |  |
| $\mathrm{I}_{\mathrm{R}}{ }^{\text {a }}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | $\mathrm{V}_{\mathrm{R}}=25 \mathrm{~V}$ |  |  | 0.5 | $\mu \mathrm{A}$ |
|  | $\mathrm{T}_{\mathrm{j}}=100^{\circ} \mathrm{ÉC}$ |  |  |  |  | 100 |  |

DYNAMIC CHARACTERISTICS

| Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :--- | :---: | :---: | :---: | :---: |
| C | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C} \quad \mathrm{V}_{\mathrm{R}}=1 \mathrm{~V} \quad \mathrm{f}=1 \mathrm{MHz}$ |  | 7 |  | pF |
| trr | $\mathrm{Tj}_{\mathrm{j}}=25^{\circ} \mathrm{C} \quad \mathrm{I}_{F}=10 \mathrm{~mA} \quad \mathrm{I}_{\mathrm{R}}=10 \mathrm{~mA} \quad \mathrm{i}_{\mathrm{rr}}=1 \mathrm{~mA}$ <br> $\mathrm{R}_{\mathrm{L}}=100 \Omega$ |  |  | 5 | ns |
| h | $\mathrm{~T}_{\mathrm{j}}=25^{\circ} \mathrm{C} \quad \mathrm{R}_{\mathrm{L}}=15 \mathrm{~K} \Omega \quad \mathrm{C}_{\mathrm{L}}=300 \mathrm{pF} \quad \mathrm{f}=45 \mathrm{MHz} \quad \mathrm{V}_{\mathrm{i}}=2 \mathrm{~V}$ | 80 |  |  | $\%$ |

* Pulse test: $t_{p} \leq 300 \mu \mathrm{~s} \quad \delta<2 \%$.

Fig. 1: Forward current versus forward voltage at different temperatures (typical values).


Fig. 2: Forward current versus forward voltage (typical values).


Fig. 3: Reverse current versus junction temperature (typical values).


Fig. 4: Reverse current versus continuous reverse voltage.


Fig. 5: Capacitance C versus reverse applied voltage $\mathrm{V}_{\mathrm{R}}$ (typical values).


PACKAGE MECHANICAL DATA
DO-35


Cooling method: by convection and conduction
Marking: clear, ring at cathode end.
Weight: 0.15 g

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